

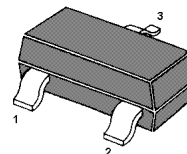
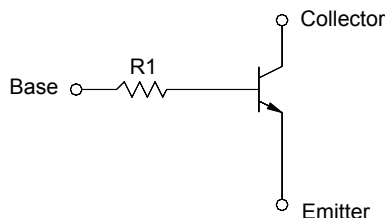
# MMBTRC110SS...MMBTRC114SS

## NPN Silicon Epitaxial Planar Transistor

for switching and interface circuit and drive circuit applications

### Features

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process



1. Base 2. Emitter 3. Collector  
SOT-23 Plastic Package

### Absolute Maximum Ratings ( $T_a = 25\text{ }^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Collector Base Voltage	$V_{CBO}$	50	V
Collector Emitter Voltage	$V_{CEO}$	50	V
Emitter Base Voltage	$V_{EBO}$	5	V
Collector Current	$I_C$	100	mA
Power Dissipation	$P_{tot}$	200	mW
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_{Stg}$	- 55 to + 150	$^\circ\text{C}$

### Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_{CE} = 5\text{ V}$ , $I_C = 1\text{ mA}$	$h_{FE}$	120	-	-	-
Collector Cutoff Current at $V_{CB} = 50\text{ V}$	$I_{CBO}$	-	-	100	nA
Emitter Cutoff Current at $V_{EB} = 5\text{ V}$	$I_{EBO}$	-	-	100	nA
Collector Emitter Saturation Voltage at $I_C = 10\text{ mA}$ , $I_B = 0.5\text{ mA}$	$V_{CE(sat)}$	-	-	0.3	V
Transition Frequency at $V_{CE} = 10\text{ V}$ , $I_C = 5\text{ mA}$	$f_T$	-	250	-	MHz
Input Resistor	MMBTRC110SS	-	4.7	-	K $\Omega$
	MMBTRC111SS	-	10	-	
	MMBTRC112SS	-	100	-	
	MMBTRC113SS	-	22	-	
	MMBTRC114SS	-	47	-	